VERIFICATION CERTIFICATE



NOT TRANSFERABLE

This Verification Certificate is hereby issued to the named GRANTEE and is VALID ONLY for the equipment identified hereon for use under the rules and regulations listed below:

GRANTEE:

Sangoma Technologies Corp.

Address:

50 McIntosh Drive, Suite 120

Markham, Ontario

Canada, L3R 9T3

Contact Person:

Mr. Michael Feldman

Phone #: 905-474 1990 ext 117

Fax #: 905-474-9223

Email Address: m.Feldman@sangoma.com

Equipment Type:

Information Technology Equipment

Product Name:

AFT Series / AFT Series

Model No.:

A104 / A301

Year of manufacture:

2005

The above product was tested by UltraTech Engineering Labs Inc. and found to comply with:

CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 -

Electromagnetic Compatibility Requirements - Information Technology

Equipment - Immunity Characteristics - Limits and Methods of

Measurements

Note(s): See attached report, UltraTech's File No.: SNG021-EN24, dated January 13, 2005 for details and conditions of Verification Compliance.



Approved by: Tri M. Luu, P.Eng. V.P. - Engineering

UltraTech

3000 Bristol Circle, Oakville, Ontario, Canada, L6H 6G4 Tel.: (905) 829-1570 Fax.: (905) 829-8050 Website: www.ultratech-labs.com Email: vic@ultratech-labs.com, Email: tri.luu@sympatico.ca





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00-034

Summary of Applicable Test Results

STANDARD	DESCRIPTION	SEVERITY APPLIED	PERFORMANCE CRITERIA MET	PERFORMANCE CRITERIA ALLOWED
IEC 61000-4-2 EN 61000-4-2	Electrostatic Discharge	 4kV Contact Discharge (Direct & Indirect) 8kV Air Discharge 	A	В
IEC 61000-4-3 EN61000-4-3 ENV 50204	Radiated RF Immunity	 3 V/m, 80-1000 MHz, 1 kHz 80% AM Modulation 3 V/m. 900MHz, 200Hz Pulse Modulation 	A	A
IEC 61000-4-4 EN 61000-4-4	Electrical Fast Transient	± 1kV on AC Lines ± 0.5 kV on I/O Lines	A	В
EN 61000-4-5	Surge Withstand Immunity	■ ± 2kV Common Mode on AC Lines	A	В
EN 61000-4-5		± 1kV Differential mode on AC lines	A	В
IEC 61000-4-6 EN 61000-4-6	Conducted RF Immunity	3V, 0.15-80 MHz, 1kHz 80% AM modulation on AC & I/O Lines	A	A
IEC 61000-4-8 EN 61000-4-8	Magnetic Field Immunity	■ 50/60 Hz, 3 A/m	A	A

DECLARATION OF CONFORMITY

APPPLICATION OF COUNCIL DIRECTIVE(S): 89/336/EEC - The EMC Directive

GRANTEE: Sangoma Technologies Corp. 50 McIntosh Drive, Suite 120

Markham, Ontario Canada, L3R 9T3

Equipment Type: Information Technology Equipment

Product Name: AFT Series / AFT Series

Model No.: A104 / A301

Year of manufacture: 2004

I, the undersigned, hereby, declare that the above device has been tested and found to comply with the following standard(s):

STANDARD(S) TO WHICH CONFORMITY IS DECLARED:

 CISPR 22:2003/EN 55022:2003 - Class A - Limits and methods of measurement of radio disturbance characteristics of Information Technology Equipment.

CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 Information Technology Equipment - Immunity Characteristics - Limits
and Methods of Measurements

Test Laboratories: Ultratech Engineering Labs Inc.

3000 Bristol Circle

Oakville, Ontario, Canada L6H 6G4

Applicant: Legal Representative in Europe:

Signature: Signature:

Full Name: Mr. Michael Feldman Full Name:

Title:

Full Address: Markham, Ontario Full Address: Canada, L3R 9T3

Phone No.: 905-474 1990 ext 117 Phone No.: Email Address: m.Feldman@sangoma.com Email Address:

ENGINEERING TEST REPORT



AFT Series / AFT Series Model No.: A104 / A301

Sangoma Technologies Corp. Applicant:

50 McIntosh Drive, Suite 120 Markham, Ontario Canada, L3R 9T3

In Accordance With

EUROPEAN STANDARD: CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 ELECTROMAGNETIC COMPATIBILITY REQUIREMENTS Information Technology Equipment **Immunity Characteristics - Limits and Methods of Measurements**

UltraTech's File No.: SNG021-EN24

This Test report is Issued under the Authority of Tri M. Luu, Professional Engineer, Vice President of Engineering UltraTech Group of Labs

Date: January 13, 2005

Report Prepared by: Chau Le

Tested by: Quan Ngo, EMC Technician

Issued Date: January 13, 2005

Test Dates: Jan. 3, 4 & 5, 2005

The results in this Test Report apply only to the sample(s) tested, and the sample tested is randomly selected.

This report must not be used by the client to claim product endorsement by NVLAP or any agency of the US Government.

UltraTech

3000 Bristol Circle, Oakville, Ontario, Canada, L6H 6G4 Tel.: (905) 829-1570 Fax.: (905) 829-8050

Email: vic@ultratech-labs.com, Email: tri.luu@sympatico.ca Website: www.ultratech-labs.com

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INTRODUCTION EXHIBIT 1.

SCOPE 1.1.

Reference:	CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003	
	Electromagnetic Compatibility Requirements, - Information Technology Equipment -	
Title	Immunity Characteristics - Limits and Methods of Measurements.	
	Immunity Characteristics - Limits and Methods of Measurements.	
Purpose of Test:	To gain EC Declaration of Conformity Compliance in accordance with CISPR 24::1997 / EN	
Turpose of Test.	55024·1998 +A1:2001 & +A2:2003	
	The immunity tests were performed in accordance with CISPR 24::1997 / EN 55024:1998	
Method of Measurements:	The immunity tests were performed in accordance with Clark 24.130 (2.13)	
1.20	+A1:2001 & +A2:2003, EN 61000-3-2, EN 61000-3-3 and EN 61000-4-2 through EN	
	61000-4-11.	
Environmental	Residential	
1	***************************************	
Classification:	 Light-industry, Commercial 	

The CISPR publication applies to information technology equipment (ITE) as defined in CISPR 22.

Harmonized standards prepared by ETIS, which cover the immunity requirements for telecommunications network equipment take precedence over this standard.

Procedures are defined for the measurement of the ITE and limits are specified which are developed for ITE and within the frequency range from 0 Hz to 400 GHz.

The object of the Standard EN 55024:1998 is to establish requirements which will provide an adequate level of intrinsic immunity so that the equipment will operate as intended in its environment.

For exceptional environment conditions, special mitigation measures may be required.

Owning to testing and performance assessment considerations, some tests are specified in defined frequency bands or at selected frequencies. Equipment which fulfils the requirements at these frequencies is deemed to fulfil the requirements in the entire frequency range form 0 Hz to 400 GHz for electromagnetic phenomena.

The object of the Standard EN 55024:1998 is to define the immunity test requirements for equipment defined in the scope in relation to continuous and transient, conducted and radiated disturbances, including electrostatic discharge (ESD)

The test requirements are specified for each port considered.

Notes:

- 1. Safety considerations are not covered in the Standard EN 55024:1998
- In special cases, situations will arise where the level of disturbance may exceed the levels specified in the Standard EN 55024:1998, for example where a hand-held terminal is used in proximity to an equipment. In these instances special mitigation measures may have to be employed.

APPLICABILITY OVERVIEW TABLES 1.2.

It may be determined from consideration of the technical characteristics and/or intended operational environment of a particular EUT that some tests are technically inappropriate. In such a case, the decision and justification not to test these parameters shall be recorded in the test report. Decisions on the applicability of individual tests shall be based on information contained in user document and/or installation instructions, and consideration of the technical design.

CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 - Information Technology Equipment - Immunity Characteristics - Limits and Methods of Measurements.

STANDARD	DESCRIPTION	SEVERITY APPLIED	PERFORMANCE CRITERIA
IEC 61000-4-2 EN 61000-4-2	Electrostatic Discharge	 4kV Contact Discharge (Direct & Indirect) 8kV Air Discharge 	В
IEC 61000-4-3 EN61000-4-3 ENV 50204	Radiated RF Immunity	 3 V/m, 80-1000 MHz, 1 kHz 80% AM Modulation 3 V/m. 900MHz, 200Hz Pulse Modulation 	A
IEC 61000-4-4 EN 61000-4-4	Electrical Fast Transient	± 1kV on AC/DC Lines ± 0.5 kV on I/O Lines	В
EN 61000-4-5	Surge Withstand Immunity	+ 2kV Common Mode on AC Lines	В
EN 61000-4-5	Surge Williams International	+ 1kV Differential mode on AC lines	В
EN 01000-4-3		± 1kV Common mode ports that connected to outdoor telecom cables	В
		± 0.5kV Common mode ports that connected to indoor telecom cables and DC input supply (if longer than 10 m)	В
IEC 61000-4-6	Conducted RF Immunity	■ 3V, 0.15-80 MHz, 1kHz 80% AM modulation on AC, DC &	A
EN 61000-4-6		I/O Lines	
IEC 61000-4-8 EN 61000-4-8	Magnetic Field Immunity	• 50 Hz, 1 A/m	A
IEC 61000-4-11	 Voltage Dips 	■ Dip 30% - 0.5 Sec. Interval on AC	С
EN 61000-4-11	 Voltage Dips Voltage Dips 	Reduction >95% for 10m Sec. interval	В
EN 61000-4-11	Voltage Interruption	Reduction >95% for 5 Sec. interval	C
IEC 61000-3-2	Harmonic Current Emissions	Class A (Other)	PASS
EN61000-3-2		Class B (Portable Equipment)	
		Class C (Lighting Equipment) or	
		Class D (Special Current Waveform)	
IEC 61000-3-3	Voltage Fluctuation and Flicker	Voltage Fluctuation	PASS
EN61000-3-3	in Low-Voltage Supply Systems	Flicker	PASS

NORMATIVE REFERENCES 1.3.

The methods and procedures used for the measurements contained in this report are details in the following reference standards:

Publication	YEAR	Title	EN/HD	Year
89/336/EEC		Council Directive on the Approximation of the Laws of the		
69/330/EEC		Member States Relating Electromagnetic Compatibility		
CISPR 24	1997	Information Technology Equipment - Immunity	EN 55024	1998
CISPR 24	1997	Characteristics - Limits and Methods of Measurements	+A1	2001
		Characteristics Emilia and Section 1	+A2	2003
IEC 50(151)	1978	International Electrotechnical Vocabulary (IEV), Chapter	-	1995
IEC 30(131)	1570	151: Electrical and Magnetic Devices		
IEC 50(161)	1990	Chapter 161: Electromagnetic Compatibility	-	1996
IEC 61000-3-2	1995	Electromagnetic Compatibility (EMC)	EN 61000-3-2	2001
IEC 01000-3-2	1555	Part 3: Limits		
		Section 2: Limits for harmonic current emissions		
		(equipment input current up to and including 16 A per		
		phase)		
IEC 61000-3-3	1994	Section 3: Limitation of voltage fluctuations and flicker in	EN 61000-3-3	1998
IEC 01000-5-5	1,,,,	low-voltage supply systems for equipment with rated		
		current up to and including 16A		
IEC 61000-4-2	1995	Part 4: Testing and measurement techniques	EM 61000-4-4	2001
IEC 01000-4-2	1,,,,	Section 2: Electrostatic discharge immunity test – Basic		
		EMC publication		
IEC 61000-4-3	1995	Radiated radio-frequency, electromagnetic field immunity	EN 61000-4-5	2001
(mod)	1330	test		
IEC 61000-4-4	1995	Section 4: Electrical fast transient/burst immunity test –	EN 61000-4-4	2001
IEC 01000-4-4	1775	Basic EMC publication		
IEC 61000-4-5	1995	Section 5: Surge immunity test	EN 61000-4-5	2001
IEC 61000-4-6	1996	Section 6: Immunity to conducted disturbances, induced by	EN 61000-4-6	2003
ILC 01000-7-0	1770	radio-frequency fields		
IEC 61000-4-11	1994	Section 11: Voltage dips, short interruptions and voltage	EN 61000-4-11	2000
IEC 01000-4-11	1997	variations immunity tests – Basic EMC publication		

EXHIBIT 2. PERFORMANCE ASSESSMENT

2.1. CLIENT INFORMATION

APPLICANT:	
Name:	Sangoma Technologies Corp.
Address:	50 McIntosh Drive, Suite 120
	Markham, Ontario
	Canada, L3R 9T3
Contact Person:	Mr. Michael Feldman
Continue	Phone #: 905-474 1990 ext 117
	Fax #: 905-474-9223
	Email Address: m.Feldman@sangoma.com

MANUFACTURER:	
Name:	Sangoma Technolgies Corp.
Address:	50 McIntosh Drive, Suite 120
	Markham, Ontario
	Canada, L3R 9T3
Contact Person:	Mr. Michael Feldman
	Phone #: 905-474 1990 ext 117
	Fax #: 905-474-9223
	Email Address: m.Feldman@sangoma.com

2.2. EQUIPMENT UNDER TEST (EUT) INFORMATION

The following information (with the exception of the Date of Receipt) has been supplied by the applicant.

Brand Name	Sangoma Technologies Corp.
Product Name	AFT Series / AFT Series
Model Name or Number	A104 / A301
Type of Equipment	Information Technology Equipment
Oscillators' Frequencies	12.352 MHz, 2.048 MHz / 12.288 MHz
CPUs' Frequencies	N/A
Power input source:	230Vac 50Hz

LIST OF COMPONENTS/PARTS OF THE EUT 2.3.

Please refer to the part list provided by manufacturer

LIST OF EUT'S PORTS 2.4.

Port Number	EUT's Port Description	Number of Identical Ports	Connector Type	Cable Type (Shielded/Non-shielded)
	T1/E1 interface on A104	4	RJ-48	Non-shielded
	DS3/E3 interface on A301	1	Coax connector	Shielded
2	DS3/E3 IIIterrace on A301			

NOTES:

- Ports of the EUT which in normal operation were connected to ancillary equipment through interconnecting (1) cables via a representative interconnecting cable to simulate the input/output characteristics.
- Ports which are not connected to cables during normal intended operation (for factory/technical services uses (2) only): None

ANCILLARY EQUIPMENT 2.5.

The EUT was tested while connected to the following representative configuration of ancillary equipment necessary to exercise the ports during tests:

Ancillary Equipment # 1	
Brand name:	Dell PC
Product Key:	MXMCA-WMZG3-C7KG2-DW2MM-X394M
	X10-23534
Cable Type:	Card edge connector
Connected to EUT's Port:	PCI interface

Ancillary Equipment # 2	
Brand name:	IBM Monitor
Model Name or Number:	8547-OAN
Serial Number:	23-NCADL
Cable Type:	Shielded
Connected to PC Port:	VGA port (HD15)

Ancillary Equipment # 3	
Brand name:	Epson Printer
Model Name or Number:	P780B
Serial Number:	1QY1048139
Cable Type:	Shielded
Connected to PC Port:	Parallel port (DB25)

Ventel Modem
EC2400-32A
350503508
Shielded
Serial port (DB9)

Ancillary Equipment # 5	
Brand name:	HP Keyboard
Part Number:	5187-1767
Serial Number:	BF34411323
Cable Type:	Shielded
Connected to PC Port:	Keyboard port (6 Pin)

Ancillary Equipment # 6	
Brand name:	Dell Mouse
Serial Number:	LNA10924947
Cable Type:	Shielded
Connected to PC Port:	Mouse port (6 Pin)

Ancillary Equipment # 7	
Brand name:	Microphone
Cable Type:	Shielded
Connected to PC Port:	1/8 inch mini jack

Ancillary Equipment # 8	
Brand name:	Headphone
Cable Type:	Shielded
Connected to PC Port:	1/8 inch mini jack

Ancillary Equipment # 9	
Brand name:	2x Polk Audio Speaker
Cable Type:	Shielded
Connected to PC Port:	1/8 inch mini jack

EXHIBIT 3. EUT OPERATING CONDITIONS AND CONFIGURATIONS DURING TESTS

3.1. CLIMATE TEST CONDITIONS

The climate conditions of the test environment are as follows:

Temperature:	21°C
Humidity:	51%
Pressure:	102 kPa
Power input source:	PCI interface

3.2. OPERATIONAL TEST CONDITIONS & ARRANGEMENT FOR TEST SIGNALS

A104 board and A301 are continuously running in the loop back mode.

3.3. BLOCK DIAGRAM OF TEST SETUP

The following drawings show details of the test setup for Electromagnetic Radiation Disturbance measurements

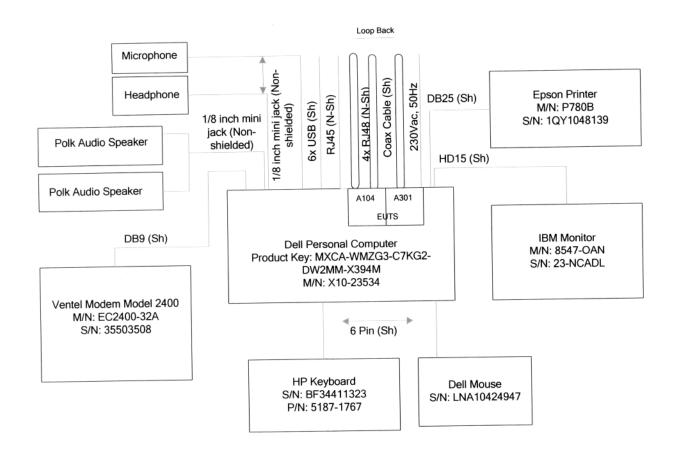


EXHIBIT 4. SUMMARY OF TEST RESULTS

4.1. LOCATION OF TESTS

All of the measurements described in this report were performed at Ultratech Group of Labs located in the city of Oakville, Province of Ontario, Canada.

4.2. SUMMARY OF EMC IMMUNITY TEST RESULTS

STANDARD	DESCRIPTION	SEVERITY APPLIED	PERFORMANCE CRITERIA MET	PERFORMANCE CRITERIA ALLOWED
IEC 61000-4-2 EN 61000-4-2	Electrostatic Discharge	4kV Contact Discharge (Direct & Indirect)8kV Air Discharge	A	В
IEC 61000-4-3 EN61000-4-3 ENV 50204	Radiated RF Immunity	 3 V/m, 80-1000 MHz, 1 kHz 80% AM Modulation 3 V/m. 900MHz, 200Hz Pulse Modulation 	A	A
IEC 61000-4-4 EN 61000-4-4	Electrical Fast Transient	 ± 1kV on AC Lines ± 0.5 kV on I/O Lines 	A	В
EN 61000-4-5	Surge Withstand Immunity	■ + 2kV Common Mode on AC Lines	A	В
EN 61000-4-5	Jange Wansama	± 1kV Differential mode on AC lines	A	В
IEC 61000-4-6 EN 61000-4-6	Conducted RF Immunity	3V, 0.15-80 MHz, 1kHz 80% AM modulation on AC & I/O Lines	A	A
IEC 61000-4-8 EN 61000-4-8	Magnetic Field Immunity	• 50/60 Hz, 3 A/m	A	A
IEC 61000-4-11 EN 61000-4-11	Voltage DipsVoltage DipsVoltage Interruption	 Dip 30% - 0.5 Sec. Interval on AC Reduction >95% for 10m Sec. interval Reduction >95% for 5 Sec. interval 	N/A	C B C
IEC 61000-3-2 EN61000-3-2	Harmonic Current Emissions	 Class A (Other) Class B (Portable Equipment) Class C (Lighting Equipment) Class D (Special Current Waveform) 	N/A	PASS
IEC 61000-3-3 EN61000-3-3	Voltage Fluctuation and Flicker in Low-Voltage Supply Systems	Voltage FluctuationFlicker	N/A	PASS PASS

4.3. MODIFICATIONS INCORPORATED IN THE EUT FOR COMPLIANCE PURPOSES

None

MEASUREMENTS, EXAMINATIONS & TEST DATA FOR EMC EXHIBIT 5. IMMUNITY

TEST PROCEDURES 5.1.

This section contains test results only. Details of test methods and procedures can be found in Exhibit 6 of this report.

Decisions on the applicability of individual tests are based on information contained in user document and/or installation instructions, and consideration of the technical design of the EUT.

MEASUREMENT EQUIPMENT USED: 5.2.

The measurement equipment used complied with the requirements of the Standards referenced in the Methods & Procedures EN 55024:1998 and EN 61000 Part 3 (Sections 2 & 3) and Part 4 (Sections 2 through 11).

PERFORMANCE CRITERIA: 5.3.

Throughout the EMC immunity tests for the EUT in these sub-paragraphs shall meet the performance criteria specified in CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003

Performance Criteria

Performance Chiena		
Criteria	During Test	After Test
	Operate as intended	Operate as intended
A	Degradation of performance	No degradation of performance
	No loss of function	No loss of function
P	Loss of function (one or more)	Operate as intended
ь	Loss of function (one of mercy)	No degradation of performance
		Functions self-recoverable
С	Loss of function (one or more)	Operate as intended
C	Loss of function (one of more)	No degradation of performance
		Functions recoverable by the operator

5.4. ELECTROSTATIC DISCHARGE @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 & EN 61000-4-2

5.4.1. LIMITS @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003

The equipment shall meet the Criteria B during the application of tests:

ELECTROSTATIC DISCHARGE LEVELS		
CONTACT DISCHARGES	AIR DISCHARGE	
<u>+</u> 2 kV and <u>+</u> 4 kV	<u>+2</u> kV, <u>+</u> 4 kV and <u>+8</u> kV	

5.4.2. METHOD OF MEASUREMENTS

Refer to Exhibit 6 of this test report & EN61000-4-2

5.4.3. TEST EQUIPMENT LIST

Electrostatic Discharge Simulator, Schaffner, Model No.: NSG-433, S/N: 00940, c/w contact discharge adapter.

The characteristics of the discharge network and operating parameters are as follows.

	AIR DISCHARGE
Charge Voltage Uo:	2-18kV ± 10%
Rise Time t _r :	5nS ± 30% @ 4kV
Half-Value width tw:	30nS ± 30% @ 4kV
Polarity:	Pos./Neg. According to HV cascade
Discharge Capacitors Cs:	150pF ± 10%
Discharge Resistor Rd:	330 Ohms ± 10%
Max. Discharge Energy:	350mJ
Test Finger:	According to IEC 61000-4-2 (8mm DIA.)

CONTACT DISCHARGE				
Charge Voltage Uo:	$2-8kV \pm 10\%$			
Rise Time t _r :	< 1nS			
Polarity:	Pos./Neg. According to HV cascade			
Peak Discharge Current:	30 Amps @ 8kV min.			
Discharge Resistor Rd:	330 Ohms ± 10%			
Test Finger:	According to IEC 61000-4-2 (Point)			

5.4.4. TEST DATA

5.4.4.1. Indirect Contact Discharge to Horizontal Coupling Plane Located underneath the EUT.

APPLIED TO EUT'S LOCATION	LEVEL (kV)	DISCHARGE	NOTE	OBSERVATION
Front	+2	10		No performance degradation was observed
110111	-2	10		No performance degradation was observed
	+4	10		No performance degradation was observed
	-4	10		No performance degradation was observed
	· ·			
Left Side	+2	10		No performance degradation was observed
Left Side	-2	10		No performance degradation was observed
	+4	10		No performance degradation was observed
	-4	10		No performance degradation was observed
Right Side	+2	10		No performance degradation was observed
rugii siii	-2	10		No performance degradation was observed
	+4	10		No performance degradation was observed
	-4	10		No performance degradation was observed
Rear	+2	10		No performance degradation was observed
	-2	10		No performance degradation was observed
	+4	10		No performance degradation was observed
	-4	10		No performance degradation was observed

5.4.4.2. Indirect Contact Discharge to Vertical Coupling Plane Located 10 cm away from the EUT.

APPLIED TO EUT'S LOCATION	LEVEL (kV)	DISCHARGE COUNT	NOTE	OBSERVATION
Front	+2	10		No performance degradation was observed
	-2	10		No performance degradation was observed
	+4	10		No performance degradation was observed
	-4	10		No performance degradation was observed
Left Side	+2	10		No performance degradation was observed
2010 2100	-2	10		No performance degradation was observed
	+4	10		No performance degradation was observed
	-4	10		No performance degradation was observed
				No performance degradation was observed
Right Side	+2	10		No performance degradation was observed No performance degradation was observed
	-2	10		No performance degradation was observed
	+4	10		No performance degradation was observed
	-4	10		No performance degradation was observed
		10		No performance degradation was observed
Rear	+2	10		No performance degradation was observed No performance degradation was observed
	-2	10		No performance degradation was observed
	+4	10		No performance degradation was observed
	-4	10		No performance degradation was observed

5.4.4.3. Direct Contact Discharge to the EUT.

Test No.	APPLIED TO EUT'S LOCATION	LEVEL (kV)	DISCHARGE COUNT	NOTE	OBSERVATION
1	Chassis of card T1 E1	+2	10		No performance degradation was observed
•		-2	10		No performance degradation was observed
		+4	10		No performance degradation was observed
		-4	10		No performance degradation was observed
					•
2	Chassis of card A301	+2	10		No performance degradation was observed
2	Chassis of card A301	-2	10		No performance degradation was observed
		+4	10		No performance degradation was observed
		-4	10		No performance degradation was observed
3	DS3/E3 connector shell	+2	10		No performance degradation was observed
3	DSS/ES connector sheri	-2	10		No performance degradation was observed
		+4	10		No performance degradation was observed

5.4.4.4. Air Discharge to the Non-conducting Parts of EUT.

Test No.	APPLIED TO EUT'S LOCATION	LEVEL (kV)	DISCHARGE COUNT	NOTE	OBSERVATION
1	4x T1/E1 interface cable	+2	10		No discharge, no performance degradation was observed
•		-2	10		No discharge, no performance degradation was observed
		+4	10		No discharge, no performance degradation was observed
		-4	10		No discharge, no performance degradation was observed
		+6	10		No discharge, no performance degradation was observed
		-6	10		No discharge, no performance degradation was observed
		+8	10		No discharge, no performance degradation was observed
		-8	10		No discharge, no performance degradation was observed
				•	•
2	2x DS3/E3 interface cable	+2	10		No discharge, no performance degradation was observed
-	ZX DSS/ES Interface case	-2	10		No discharge, no performance degradation was observed
		+4	10		No discharge, no performance degradation was observed
		-4	10		No discharge, no performance degradation was observed
		+6	10		No discharge, no performance degradation was observed
		-6	10		No discharge, no performance degradation was observed
		+8	10		No discharge, no performance degradation was observed
		-8	10		No discharge, no performance degradation was observed

PHOTOGRAPHS OF TEST SETUP 5.4.5.

Refer to the following photographs for setup and arrangement of equipment under tests.



5.5. R.F. ELECTROMAGNETIC FIELDS @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 & EN 61000-4-3

5.5.1. LIMITS @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003

The equipment shall meet the Criteria A during the application of tests:

RADIO FREQUENCY E	LECTROMAGNETIC FIELD
Test Frequency	RF Signal
80 to 1000 MHz	3 V/m, 80%AM modulation with 1 kHz Sine Wave Signal

5.5.2. METHOD OF MEASUREMENTS

Refer to Exhibit 6 of this test report & EN61000-4-3

Setup - 3 V/n	Setup - 3 V/m Amplitude Modulated & Pulse Modulated Fields				
Method Used:	Biconnilog antenna and full anechoic chamber				
Minimum Field Strength Exposure:	3 V/m (measured un-modulated carrier)				
Frequency Range/Modulation	■ 80-400 MHz, 80% AM modulation using 1 kHz sine modulating signal				
Trequency rungers	 400-1000 MHz, 80% AM modulation using 1 kHz sine modulating signal 				
	• 900 ± 5 MHz, 200 Hz Pulse Modulation				
Antenna Polarization:	Vertical & Horizontal				
Test Distance:	3m from faces of the EUT to geometric center of radiating antenna				
Frequency Steps:	 200 kHz in 26 - 50MHz band 				
Trequency steps:	 500 kHz in 50 - 100 MHz band 				
	■ 1 MHz in 100- 200 MHz band				
	 2 MHz in 200 - 500 MHz band 				
	• 5 MHz in 500 - 1000 MHz band				
Dwell Time:	1000 mS minimum				
Sweep Rate:	1 x 10 ⁻³ decades/second minimum				
Exposures:	Front, Back, Left, Right, Top, Bottom of the EUT				

TEST EQUIPMENT LIST 5.5.3.

EQUIPMENT DESCRIPTION						
Braden Fully Anechoic Chamber, 12'x24'x12', Ferrite Tiles on all six surfaces (walls, ceiling and floor)						
Emco 3143 Biconilog Antenna, S/N 1028, 26-1300 MHz, 1.3kW - 50Ω						
Holiday Industries HI-3004 Field Strength Meter and Isotropic Probe, S/N 56562, 500kHz - 1.3GHz, 1 - 30V/m ranges						
Electrometrics EF4, Field strength Meter with 4 Isotropic Probes, S/N 106-1,2,3,4						
10kHz - 1000MHz, 1-300V/m ranges						
Boonton 92BD, RF Voltmeter, S/N 2406, 10kHz - 1000MHz 1mV-300V ranges						
Eaton Advanced Electronics 3551B, RF Power Amplifier, S/N 189654, 50Watts, 100-520 MHz						
Instruments for Industry IFI 404, RF Power Amplifier, S/N, 500Watts, 10kHz - 220MHz						
ENI 5100L, RF Power Amplifier, S/N 1112-03046, 100Watts, 1-400MHz						
Kalmus 720FC, RF Power Amplifier, S/N 062293-5, 40Watts, 400-1000 MHz						
Amplifier Research AR 50A220, RF Power Amplifier, S/N 13362, 50Watts, 10kHz-220MHz						
Fluke 6061A RF Synthesized Signal Generator, S/N 4770301, 10kHz-1000MHz						
Keithley 2000 Digital Multimeter, S/N 0592806, 6 1/2 digits with 10 channel scanner card & GPIB options						
Trillium 486DX66 Personal Computer with GPIB card, S/N 930583						
Ultratech EMC Control Software for Windows, Version EMC2000, Rev 1.0						
Hewlett Packard 7450, 6 pen Plotter, S/N 2848A09939						
Lightwave Communications FO-232, Fiber Optic RS-232 Modems, S/N 32961						
HI-TRON MTC-4EO2, CCTV Camera monitoring system, S/N 20100413						
Solar Electronic 7314-1016R, 2 x 10 MFD R.F. Capacitors						

TEST DATA 5.5.4.

EUT Face	Radiating	Electric Fields @ 3 V/m	Electric Field @ 3 V/m, 900±5 MHz, 200 Hz Pulse Modulation	
Exposed	Antenna Polarization	80-1000 MHz, 80% AM Mod with 1 kHz Sine Wave Signal		
Front	Horizontal	No performance degradation was observed:	No performance degradation was observed:	
	Vertical	No performance degradation was observed:	No performance degradation was observed:	
Back	Horizontal	No performance degradation was observed:	No performance degradation was observed:	
	Vertical	No performance degradation was observed:	No performance degradation was observed:	
Left Side	Horizontal	No performance degradation was observed:	No performance degradation was observed:	
	Vertical	No performance degradation was observed:	No performance degradation was observed:	
Right Side	Horizontal	No performance degradation was observed:	No performance degradation was observed:	
_	Vertical	No performance degradation was observed:	No performance degradation was observed:	
			<u> </u>	
Тор	Horizontal	No performance degradation was observed:	No performance degradation was observed:	
	Vertical	No performance degradation was observed:	No performance degradation was observed:	
Bottom	Horizontal	No performance degradation was observed:	No performance degradation was observed:	
	Vertical	No performance degradation was observed:	No performance degradation was observed:	

5.5.5. PHOTOGRAPHS OF TEST SETUP

Refer to the following photographs for setup and arrangement of equipment under tests.



ELECTRICAL FAST TRANSIENT @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 5.6. & EN 61000-4-4

LIMITS @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 5.6.1.

The equipment shall meet the Criteria B during the application of tests:

FAST TRANSIENT COMMON MODE					
Port Tested	Test Levels				
AC Mains Input Ports	 0.5 kV Peak, Tr/Th = 5/50 nS, Rep Frequency: 5 kHz, Test duration = 1 minute 				
AC Mains input i one	 1.0 kV Peak, Tr/Th = 5/50 nS, Rep Frequency: 5 kHz, Test duration = 1 minute 				
DC, Signal, Control, Telecom I/O Ports (with	 0.5 kV Peak, Tr/Th = 5/50 nS, Rep Frequency: 5 kHz, Test duration = 1 minute 				
cables longer than 3 m)					

METHOD OF MEASUREMENTS 5.6.2.

Refer to Exhibit 6 of this test report & EN61000-4-4

TEST EQUIPMENT LIST 5.6.3.

No.	Equipment Descriptions	Equipment Specifications
No. 1	Equipment Descriptions Microprocessor Controlled E-Class Series 400 ET/Burst Test Generator, by KeyTek Instrument Corp., Model E420, Serial No.: 9205213: Open Circuit Output Voltage: Short Circuit Output Current: Waveshape of Surge Voltage and Current:	 Up to 4.4 kV (10kHz) and up to 8kV (2.5kHz) 0.25kA min, 2kA max. meet figure 2 and 3 of table 2 specified in IEC 61000-4-4 50 Pulse Rise Time: 5nS ± 30% Pulse Duration: 50nS ± 30% Burst Train Repetition Rate: 1 kHz to 10 kHz Burst Train Duration: 1 to 20mS Burst Period: 0.3 to 5 seconds Generator Source Impedance: 50 Ohms
	 Generator Source Impedance: Polarity of the Surge: Internal or External Generator Trigger: Number of Tests: 	 Polarity of the Surge: positive/negative Internal or External Generator Trigger: internal Number of Tests: at least 5 positive and 5 negative at the selected points. 50 Ohms Positive/negative Internal At least 5 positive and 5 negative at selected points.
2	Coupling Clamp, by KeyTek Instrument, Model CCL-801/S, S/N: 9211339. Characteristics: typical coupling capacitance between cable and clamp: Usable diameter range of round cables: Insulation withstanding capability: 5kV min (test pulse 1.2/50uS)	 50 pF to 200 pF 4mm to 40mm 5 kV minimum (test pulse: 1.2/50 μS)
3	IBM PS/1 Personal Computer with National Instruments GPIB Card and Keytek E-Class Software control. Fiber optic RS-232 link to ET Simulator.	

File #: SNG021-EN24 January 13, 2005

5.6.4. TEST DATA

5.6.4.1. CABLE TESTED: AC INPUT PORT (Non-shielded Cable)

AC LINES	+ 0.5 kV	- 0.5 kV	+ 1.0 kV	- 1.0 kV
APPLIED G, N, L	No performance	No performance	No performance	No performance degradation was observed
3, 11, 2	degradation was observed	degradation was observed	degradation was observed	No performance degradation
G, N	No performance	No performance	No performance	was observed
3, 11	degradation was observed	degradation was observed	degradation was observed	No performance degradation
G, L	No performance	No performance	No performance	was observed
-, -	degradation was observed	degradation was observed	degradation was observed	No performance degradation
N, L	No performance	No performance	No performance	was observed
, –	degradation was observed	degradation was observed	degradation was observed	No performance degradation
G	No performance	No performance	No performance degradation was observed	was observed
	degradation was observed	degradation was observed		No performance degradation
V	No performance	No performance	No performance	was observed
	degradation was observed	degradation was observed	degradation was observed	No performance degradation
L	No performance	No performance	No performance	was observed
_	degradation was observed	degradation was observed	degradation was observed	was observed

^{*} G: ground, N: neutral, L: Live (Hot)

5.6.4.2. CABLE TESTED: I/O PORTS WITH CABLES > 3 meters

5.6.4.2.1. Cable #1: T1/E1 Interface # 1 RJ48 (Non-shielded)

5.0.4.2.1.	5.0.4.2.1. Capic #1. 11/21 Intertact			
EFT VOLTAGE LEVEL				
+ 0.5 kV - 0.5 kV				
No performance degradation was observed No performance degradation was observed				

5.6.4.2.2. Cable #2: T1/E1 Interface # 2 RJ48 (Non-shielded)

EFT VOLTAGE LEVEL		
No performance	+ 0.5 kV degradation was observed	- 0.5 kV No performance degradation was observed

5.6.4.2.3. Cable #3: DS3/E3 Interface (Shielded)

EFT VOLTAGE LEVEL		
No performance	+ 0.5 kV degradation was observed	- 0.5 kV No performance degradation was observed

5.6.4.2.4. Cable #4:

Cable #4: T1/E1 Interface #3 RJ48 (Shielded)

3.0.4.2.4.				
EFT VOLTAGE LEVEL				
+ 0.5 kV - 0.5 kV				
No performance degradation was observed No performance degradation was observed				

5.6.4.2.5. Cable #4: T1/E1 Interface #4 RJ48 (Shielded)

5.0.4.2.5.	5.0.4.2.5. Cubic # 11 11/21			
EFT VOLTAGE LEVEL				
+ 0.5 kV - 0.5 kV				
No performance	e degradation was observed	No performance degradation was observed		

5.6.5. PHOTOGRAPHS OF TEST SETUP

Refer to the following photographs for setup and arrangement of equipment under tests.



5.7. R.F. CONDUCTED IMMUNITY @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 & EN 61000-4-6

5.7.1. LIMITS @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003

The equipment shall meet the Criteria A during the application of tests:

RF CONDUCTED COMMON MODE		
Port Tested	Test Frequency	RF Signals
AC Mains I/O Power Port	150 kHz to 80 MHz	3 V, 80%AM modulation with 1 kHz Sine
		Wave Signal. Note 1
Signal, Control & Telecom I/O Ports (with	150 kHz to 80 MHz	3 V, 80%AM modulation with 1 kHz Sine
cable longer 3 m)		Wave Signal. Note 1
DC I/O Power Ports	150 kHz to 80 MHz	3 V, 80%AM modulation with 1kHz Sine
		Wave Signal. Note 1

5.7.2. METHOD OF MEASUREMENTS

Refer to Exhibit 6 of this test report & EN61000-4-6

5.7.3. TEST EQUIPMENT LIST

EQUIPMENT DESCRIPTION		
RF Shielding, Chamber, 8'x12'x8', 100dB attenuation		
Boonton 92BD, RF Voltmeter, S/N 2875, 10kHz - 1000MHz 1mV-300V ranges		
Instruments for Industry IFI 404, RF Power Amplifier, S/N, 500Watts, 10kHz - 220MHz		
Amplifier Research AR 50A220, RF Power Amplifier, S/N 13362, 50Watts, 10kHz-220MHz		
Gigatronics 60601A, RF Synthesized Signal Generator, S/N 5130408, 10kHz-1000MHz		
Fluke 8840A Digital Multimeter, S/N 431207, 5 1/2 digits GPIB options		
Rhode & Schwarz MDS-21, Absorbing Clamp, S/N 8332231/005, 30-1000MHz		
Rhode & Schwarz ESH3Z, 2 Wire T-LISN, S/N, 150ohms, 6 watts		
Fischer FCC-120-9, 801.6 Bulk Current Injection Clamp, S/N 53		
Fischer FCC-M4-50, 801.6 coupling/de-coupling network, S/N 99, 150ohm, 6 watts		
Fischer FCC-M3-25, 801.6 coupling/de-coupling network, S/N 72, 150ohm, 6 watts		
Fischer FCC-M3-25, 801.6 coupling/de-coupling network, S/N 73, 150ohm, 6 watts		
Fischer FCC-M3-25, 801.6 coupling/de-coupling network, S/N 39, 150ohm, 6 watts		
Fischer FCC-M2-25, 801.6 coupling/de-coupling network, S/N 101, 150ohm, 6 watts		
Fischer FCC-AF9, 801.6 coupling/de-coupling network, S/N 102, 150ohm, 6 watts		
Fischer FCC-AF25, 801.6 coupling/de-coupling network, S/N 103, 150ohm, 6 watts		
Fischer FCC-S1, 801.6 coupling/de-coupling network, S/N 104, 150ohm, 6 watts		
Fischer FCC-T2, 801.6 coupling/de-coupling network, S/N 20, 150ohm, 6 watts		
Fischer FCC-T4, 801.6 coupling/de-coupling network, S/N 23, 150ohm, 6 watts		
Trillium 486DX66 Personal Computer with GPIB card		
Ultratech EMC Control Software for Windows, Version EMC2000, Rev 1.0		
Lightwave Communications FO-232, Fiber Optic RS-232 Modems, S/N 32961		
HI-TRON MTC-4EO2, CCTV Camera monitoring system, S/N 20100413		
Solar Electronic 7314-1016R, 2 x 10 MFD R.F. Capacitors		

5.7.4. TEST DATA

5.7.4.1. Test Signals

Method Used:	Direct Coupling using Coupling/De-coupling Networks	
Severity Level Used:	3 V (measured un-modulated carrier)	
Frequency Range/Modulation	■ 150 kHz to 80 MHz, 80% AM modulation using 1 kHz sine modulating	
	signal	
Frequency Steps:	■ 1 kHz in 100 – 200 kHz band	
	■ 2 kHz in 200 – 500 kHz band	
	■ 5 kHz in 500 – 1 MHz band	
	■ 10 kHz in 1 – 2 MHz band	
	■ 20 kHz in 2 – 5 MHz band	
	■ 50 kHz in 5 – 10 MHz band	
	■ 100 kHz in 10 – 100 MHz band	
	■ 1 MHz in 100 – 200 MHz band	
Dwell Time:	1000 mS minimum	
Sweep Rate:	1 x 10 ⁻³ decades/second minimum	

5.7.4.2. AC Power Cable

CABLE TYPE:	Non-shielded		
CABLE LENGTH:	> 6 feet		
COUPLING/DECOUPLING NETWORK:	FCC-801-M3-25 S/N: 72		
OBSERVATION:	No performance degradation was observed		

5.7.4.3. DS3/E 3 Interface Coax Cable

CABLE TYPE:	Shielded		
CABLE LENGTH:	> 6 feet		
COUPLING/DECOUPLING NETWORK:	FCC-801-C1-BNC-50 S/N: 23		
OBSERVATION:	No performance degradation was observed		

5.7.4.4. T1/E1 W1G1 Interface RJ48 Cable

CABLE TYPE:	Non-shielded		
CABLE LENGTH:	> 6 feet		
COUPLING/DECOUPLING NETWORK:	F-120-9 S/N: 53		
OBSERVATION:	No performance degradation was observed		

5.7.4.5. T1/E1 W2G1 Interface RJ48 Cable

CABLE TYPE:	Non-Shielded	
CABLE LENGTH:	> 6 feet	
COUPLING/DECOUPLING NETWORK:	F-120-9	S/N: 53
OBSERVATION:	No performance degradation was observed	

T1/E1 W3G1 Interface RJ48 Cable 5.7.4.6.

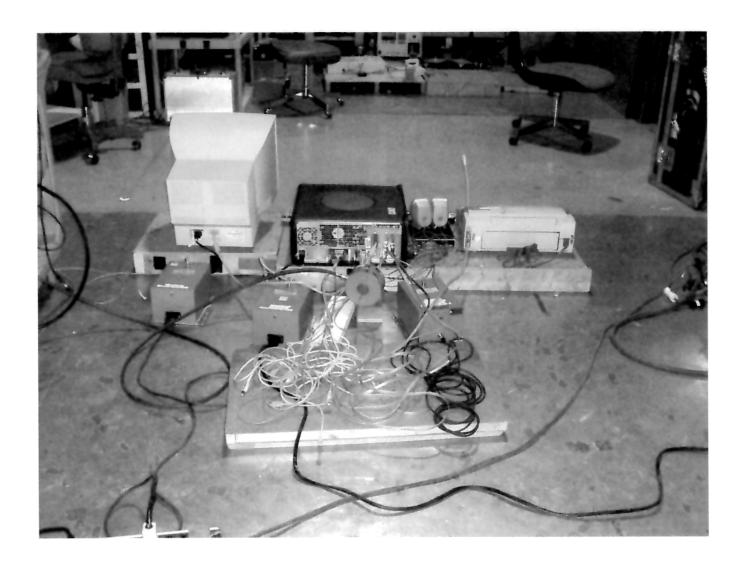
CABLE TYPE:	Non-Shielded	
CABLE LENGTH:	> 6 feet	
COUPLING/DECOUPLING NETWORK:	F-120-9	S/N: 53
OBSERVATION:	No performance degradation was observed	

T1/E1 W4G1 Interface RJ48 Cable 5.7.4.7.

CABLE TYPE:	Non-Shielded	
CABLE LENGTH:	> 6 feet	
COUPLING/DECOUPLING NETWORK:	F-120-9	S/N: 53
OBSERVATION:	No performance degradation was observed	

5.7.5. PHOTOGRAPHS OF TEST SETUP

Refer to the following photographs for setup and arrangement of equipment under tests.



5.8. POWER MAGNETIC FIELD IMMUNITY @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003 & EN 61000-8

5.8.1. LIMITS @ CISPR 24::1997 / EN 55024:1998 +A1:2001 & +A2:2003

The equipment shall meet the Criteria A during the application of tests:

FREQUENCY	MAGNETIC FIELD	DEGRADATION ALLOWED
(Hz)	(A/m)	
50 Hz	3.0	No degradation allowed
50 Hz	30.0	CRT display interference allowed

5.8.2. METHOD OF MEASUREMENTS

Refer to Exhibit 6 of this test report & EN 61000-4-8

5.8.3. TEST EQUIPMENT LIST

	EQUIPMENT DESCRIPTION		
1.	Elgar AC Power Supply, Model 1751SL-11, SN 0115, 1750VA- 4KHz AC Source		
2.	Elgar AC Power Supply, Model 1751B, SN 1438, 1750VA- 4KHz AC Source		
3.	Realistic Power Amplifier, Model MPA-45, SN 91130919, 35 Watts-3 MHz		
4.	Tabor 50MHz Arbitrary Waveform Generator, Model AWG-7223, S/N 0132		
5.	Valhalla Digital Power Analyzer, S/N 3-5106.		
6.	Phillips Digital Storage Scope, Model 3320A, SN DQ 646, 250MS/s Dual channel DSO		
7.	vantest Digital Spectrum Analyzer, Model 9211E, SN 82020336, 16bit-100KHz FFT Analyzer		

5.8.4. TEST DATA

TEST METHOD:	Using a Helmholtz Coil.	
TEST SITES OF EUT	MAGNETIC FIELD FREQUENCY & INTENSITY	OBSERVATION & COMMENTS
FRONT To BACK	50/60 Hz, 3 A/m	No performance degradation was observed
LEFT TO RIGHT	50/60 Hz, 3 A/m	No performance degradation was observed
TOP TO BOTTOM	50/60 Hz, 3 A/m	No performance degradation was observed

PHOTOGRAPHS OF TEST SETUP 5.8.5.

Refer to the following photographs for setup and arrangement of equipment under tests.



EXHIBIT 6. MEASUREMENT METHODS FOR EMC IMMUNITY MEASUREMENTS

6.1. ELECTROSTATIC DISCHARGE REQUIREMENTS @ EN 61000-4-2

6.1.1. INTRODUCTION

These tests were conducted on a sample of the equipment for the purpose of Verification compliance with EN 61000-4-2 - Electromagnetic Compatibility Requirements, Part 2: Electrostatic Discharge Requirements.

The problem of protecting equipment against the discharge of static electricity has gained considerable importance for manufacturers and users. The extensive use of microelectronics components has emphasized the need to define the aspects of the problem and to seek a solution in order to enhance product/system reliability. The problem of static electricity accumulation and subsequent discharges becomes more relevant for uncontrolled environments and the widespread application of equipment and systems in a wide range of industrial plants.

Equipment may also be subjected to electromagnetic energies whenever discharges occur from personnel to nearby object. Additionally, discharges can occur between metal objects, such as chairs and tables, in the proximity of equipment.

The effect of operator discharge may be a simple malfunction of the equipment or damage of electronic components. The dominant effects can be attributed to the parameters of the discharge current (rise time, duration, etc..)

The generation of electrostatic charges is especially favored by the combination of synthetic fabrics and dry atmosphere. There are many possible variations in the charging process. A common situation is one in which an operator walks over a carpet and at each step loses or gains electrons from his body to the fabric. Friction between the operator's clothing and his chair can also produce an exchange of charges. The operator's body may be charged either directly or by electrostatic induction's; in the latter case, a conducting carpet will give no protection unless the operator is adequately earthened to it.

Electrostatic potentials exceeding 15,000 volts are not uncommon in carpeted office environments where humidity levels are relatively low. Too the human body, air discharges become noticeable at about 4,000 volts. At about 8,000 volts, air discharges start becoming uncomfortable and the discharge is just audible. At 15,000 volts, air discharges are downright unpleasant and the spark arcs across 1 cm air gaps with a bluish tint accompanied by a loud crack. At these levels, direct air discharges to printed circuit boards can cause permanent damage to programmable and memory logic.

6.1.2. OBJECTIVE

The objective of this test is to determine the degradation of the performance of the EQUIPMENT UNDER TEST (EUT) when subjected to electrostatic discharges; the electrostatic discharges may occur from the personnel to the objects near the EUT (indirect discharge) or directly to EUT (direct discharge).

6.1.3. APPLICATION OF THE STATIC ELECTRICITY DISCHARGES

Applicable discharge locations (HCP, VCP, points, surfaces etc ...), discharge methods (contact or air), voltage level, polarity, number of discharges, results and etc... were recorded in the TEST DATA.

6.1.4. DIRECT APPLICATION OF DISCHARGES TO EUT

Direct contact discharge was applied to all conductive points. Where contact discharge could not be obtained on insulated surfaces, air discharge was applied.

Wherever applicable. The direct application of discharges to EUT was performed as follows:

- User accessible points and surfaces of EUT during normal operation.
- Points accessible for maintenance purposes (not allowed unless agreed by the manufacturer and user).
- The test was performed with single discharges on pre-selected points. The time interval between successive single discharges (at least 10 discharges) was at least 1 second. Longer intervals might be necessary to determine whether a system failure had occurred.

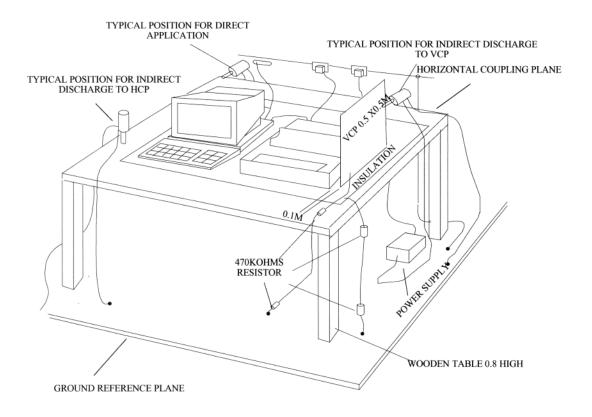
Note: The points to which the discharges were applied, and test voltage polarity to be used might be selected by means of an exploration carried out at a repetition rate of 20 discharges per second, or more.

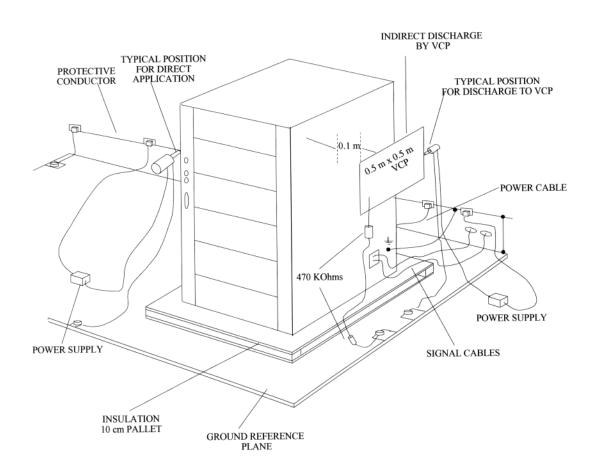
- ESD generator was held perpendicular to the surface to which the discharge was applied, this improved the repeatability of test results.
- The discharge return cable of the generator was always kept at a distance of at least 0.2m from the EUT whilst the discharged was being applied.
- In the case of contact discharges, the tip of the discharge electrode touched the EUT, before the discharge switch was operated.
- If the coating was not declared as insulating coating by the equipment manufacturer, then the pointed tip of the generator was used to penetrate the coating so as to make contact with the conducting substrate.
- In the case of air discharges, the round discharge tip of the discharge electrode was approached as fast as possible (without causing mechanical damage) to touch the EUT. After each discharge, the ESD generator (discharge electrode) was removed from the EUT. This procedure was repeated until the discharges were completed. In the case of the air discharge test, the contact relay, which was used for contact discharge, was removed.

INDIRECT APPLICATION OF DISCHARGES TO EUT 6.1.5.

Discharges to objects placed or installed near to the EUT were simulated by applying the discharges of the ESD generator to a coupling plane, in the contact discharge mode.

- Horizontal Coupling Plane (HCP) under the EUT: At least 10 single discharges (in the most sensitive polarity) were applied to the HCP, at points on each side of the EUT (front, rear, left and right sides). The ESD generator was positioned vertically at a distance of 0.1 m from the EUT, with the discharge electrode touching the coupling plane.
- Vertical Coupling Plane (VCP) under the EUT: At least 10 single discharges (in the most sensitive polarity) were applied to the center of one vertical edge of the VCP. The VCP, of dimensions 0.5m x 0.5m, was placed parallel to, and positioned at a distance of 0.1 m from the EUT. Discharges were applied to the VCP, with this plane in sufficient different positions that the four faces of the EUT are completely illuminated.





6.1.6. RADIATED IMMUNITY REQUIREMENTS @ EN 61000-4-3

6.1.7. INTRODUCTION

These tests were conducted on a sample of the equipment for the purpose of Verifying compliance with EN 61000-4-3 - Electromagnetic Compatibility for Industrial-Process Measurement and Control Equipment, Part 3: Immunity to radio-frequency radiated electromagnetic fields.

Most electronic equipment is in some manner affected by electromagnetic radiation. This radiation is frequently generated by such sources as the small hand-held radio transceivers that are used by operating, maintenance, and security personnel, fixed station radio, television transmitters, vehicle radio transmitters, and various industrial electromagnetic sources.

In addition to electromagnetic energy deliberately generated, there is spurious radiation caused by devices such as welders, thyristors, fluorescent lights, switches operating inductive loads, etc. For the most part, this interference manifests itself as conducted electrical interference and, as such, is dealt with in other parts of the standard. Methods employed to prevent effects from electromagnetic fields will normally also reduce the effects from these sources.

The electromagnetic environment is determined by the strength of the electromagnetic field (field strength in volts per meter). The field strength is not easily measured without sophisticated instrumentation nor is it easily calculated by classical equations and formulae because of the effect of surrounding structures or the proximity of other equipment that will distort and/or reflect the electromagnetic waves.

6.1.8. OBJECTIVE

The objective of this test is to determine the degradation of the performance of the EQUIPMENT UNDER TEST (EUT) when subjected to radio-frequency radiated electromagnetic fields at levels which are typical of commercial environments.

6.1.9. UNIT OF MEASUREMENTS

Measurements of radiated field strengths are reported in units of volts per meter [V/m] at the distance specified in the report, where it is applicable.

6.1.10. LOCATIONS OF TEST SITE

The Radiated Immunity Tests were performed in UltraTech's anechoic chamber, 24'(L) by 12'(W) by 12'(H).

6.1.11. TEST PROCEDURES

The radiated immunity measurements were conducted in accordance with IEC 61000-4-3, Electromagnetic Compatibility Requirements - Generic Immunity Standard - Part 3: Immunity to Radiated Fields.

The radiating antenna method is used for exposing the EUT to radiated electromagnetic waves. The tests are carried out in a fully shielded anechoic 12'x24'x12' chamber to contain the high fields generated so as not to interfere with local communications.

A uniform field of 0 to+6dB (1 to 2 times the required field strength) covering 1.5x1.5 meters square is established using an un-modulated carrier within the anechoic chamber using a 16 point field calibration as per the requirements of the standard. The calibration is performed on an un-modulated carrier using an isotropic field strength meter and probe. The probe is placed at a height of 1.5 meter from the floor of the chamber, at a distance of 3 meters from the geometric center of the biconi-log antenna. The frequency is swept over the amplifier range and the signal generator level at each frequency step is adjusted to maintain a field of 1.5 times the required field strength at that point to within a 0 to +10% tolerance. (Since the field is allowed to vary between 1 to 2 times within the test area, setting the center point of the area to 1.5 times the required field will ensure an average field within the required 0 to +6dB tolerance requirements). The adjusted level at each frequency is recorded in a calibration file and the process is repeated for each antenna polarization, each amplifier range and for each field strength calibration level. After the single point leveled calibration is performed, measurements of the field strength using the calibration file at sixteen 50cm equidistant points within the square test area is performed and 12 out of 16 points (75% of the area) at each frequency step must fall within the uniformity criteria before the chamber is deemed to meet the uniformity criteria required by the standard.

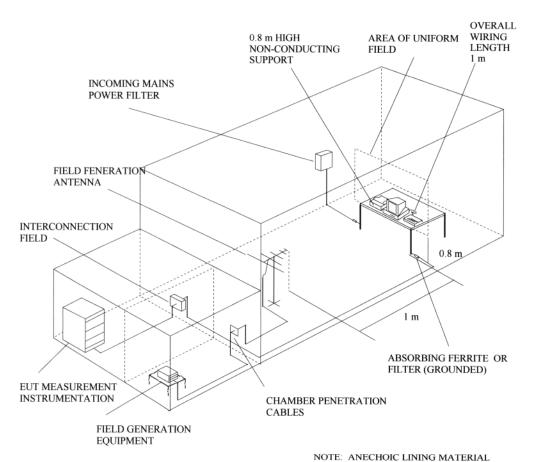
Prior to each test, a verification sweep using the appropriate calibration file is performed on the empty test volume to ensure

that the field is within specification. For floor mounted equipment, the field strength is also measured at a 40 cm height and reported in the test result section of the report.

A maximum step size of 1% of the fundamental is used in accordance with the standard and the calibration data entered into a file and a dwell time of at least 1 second is used to maintain a sweep rate of no greater than 1.5x10-3 decades/S. If it is determined that the EUT cannot respond within a one second time frame, the dwell time is increased appropriately. The geometric center of the radiating antenna is positioned 3 meters away from the EUT and both polarization's of the antenna is used. All six faces (four sides, top and bottom) of the EUT are then selected for direct exposure to the electromagnetic fields unless the EUT is large whereby the four sides are selected. The EUT is configured with all ports connected to support/ancillary or simulation equipment with cable lengths to provide for at least 1 meter exposure in the field.

During the application of the EM field, the field strength in the vicinity of the EUT is monitored to determine what the actual field strength the EUT is being subjected to since distortion of the calibrated field is expected once the EUT is installed within the test volume. Should a failure occur, the field strength at that frequency can be manually set to determine the immunity threshold of the device under test.

The performance of the EUT is monitored for any degradation during the application of the field using closed circuit monitors, fiber-optic coupled RS-232 serial interfaces or waveform monitoring using oscilloscopes or chart recorders.



ON WALLS & CEILING HAS BEEN
OMITTED FOR CLARITY

EXAMPLE OF SUITABLE TEST FACILITY

6.2. ELECTRICAL FAST TRANSIENT REQUIREMENTS @ EN 61000-4-4

6.2.1. INTRODUCTION

These tests were conducted on a sample of the equipment for the purpose of Verifying compliance with EN 61000-4-4, Electromagnetic Compatibility for Industrial-Process Measurement and Control Equipment, Part 4: Electrical Fast Transient/Burst Requirements.

6.2.2. OBJECTIVE

The objective of this test is to determine the degradation of the performance of the EQUIPMENT UNDER TEST (EUT) when subjected to repetitive fast transients (bursts), on power supply, I/O signal, data or control lines.

Types of transient interference are those originating from switching transients (interruption inductive loads, relay contact bounce, etc...)

The actual test level will be stated in the measurement data in this report.

6.2.3. TEST PROCEDURES

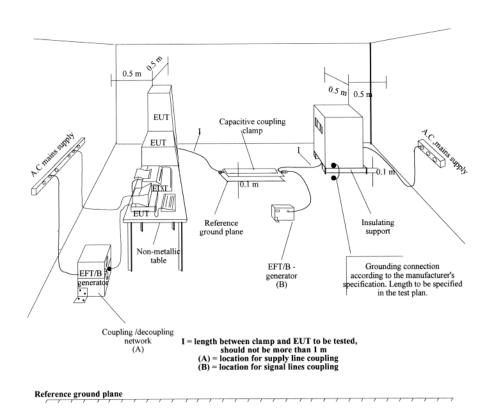
- In the case of floor-standing equipment, the EUT's was placed on a ground reference plane and insulated from it by an insulating support about 0.1 m thick.
- In the case of table-top equipment, the EUT was located on the 1m(wide)x1.5m(long) non-conducting table which was raised 0.8 meters above the ground plane.
- The reference ground was an aluminum sheet, sizes: 1.2m(wide)x1.8(long)x0.25m(thick). The reference ground plane was connected to the projective earth and projected beyond the EUT by at least 0.1m. The connection of ground cables to the reference ground plane and all bondings were made in the manner to provide the minimum inductance.
- The EUT was arranged and connected according to its normal installation requirements; the minimum distance between
 the EUT and all other conductive structures, except the reference ground plane beneath the EUT, was at least 0.5 meter.
- The EUT was connected to the earthing system accordance with the manufacturer's installation specifications, no additional earthing connection was made.
- The coupling devices were coupled to the lines between the EUT and the de-coupling network or between two units of
 equipment involved in the test.
- Using the coupling clamp, the minimum distance between the coupling plates and all other conductive structures, except
 the reference ground plane beneath the coupling clamp, was 0.5m.
- The length of the signal and power lines between the coupling device and the EUT was less than 1 meter (If the manufacturer provides a non-detachable supply cable more than 1 m long with the equipment, the excess length of this cable was gathered into a flat coil with a 0.4m diameter and situated at a distance of 0.1m above the ground reference plane)
- The distance of 1m between EUT and the coupling device was maintained.

6.2.3.1. Test on the Power Supply Lines and on Protective Earth Terminals

Test voltage was applied between each of the power supply conductors and the protective earth at the power supply outlet to which the EUT was designed to be connected.

6.2.3.2. Test on I/O Circuits and Communication Lines

- As far as possible, the capacitive coupling clamp was used for coupling the test voltage onto the lines. If the clamp
 cannot be used due to mechanical problems (size, cable routing) in cabling, it may be replaced by a tape or conductive
 foil enveloping the lines under test. The capacitance of this coupling arrangement with foil or tape should be equivalent
 to that of the standard coupling clamp.
- The ET/B generator was coupled to the terminals of the lines via discrete 100pF capacitors instead of the distributed capacitance of the clamp or of the foil arrangement. Grounding of the coaxial cable from the test generator was made in vicinity of the coupling point. Application of the test voltage to the connectors (hot wires) of coaxial or shielded communications lines was not permitted.



GENERAL TEST SET-UP FOR LABORATORY TYPE TESTS

6.3. CONDUCTED RF IMMUNITY @ EN 61000-4-6

6.3.1. INTRODUCTION

These tests were conducted on a sample of the equipment for the purpose of Verification compliance with EN 61000-4-6 - Electromagnetic Compatibility for Electrical and Electronic Equipment, Conducted Immunity Requirements.

The source of disturbance covered by this standard is basically electromagnetic field that may act on the whole length of cables connected to an installed equipment. The dimensions of the disturbed equipment, mostly a sub-part of a larger system, are assumed to be small compared with the wavelengths involved. The in-going and out-going leads; e.g. Mains, communications lines, interface cables, will therefore behave as passive receiving antenna networks because they can be several wavelengths long. Between these antenna networks, the vulnerable or susceptible equipment is exposed to currents flowing through the equipment.

Cable systems connected to an equipment are assumed to be in resonant mode ($\lambda/4$, $\lambda/2$, open or folded dipoles) and as such represented by coupling and de-coupling network systems having a common mode impedance of 150 ohms towards a ground reference plane.

6.3.2. OBJECTIVE

The objective of this test is to determine the degradation of the performance of the EQUIPMENT UNDER TEST (EUT) when subjected to radio frequency disturbances coupled to cables connected to power mains, signal lines and earth connections. The rf disturbance is in the frequency range of 9KHz to 80MHz.

The actual test level will be stated in the measurement data in this report.

6.3.3. TEST SETUP AND APPLICATION

A metal ground reference plane larger than the dimensions of the EUT by at least 20cm is used. This ground reference plane is the floor of the shielded room where the tests were conducted to minimize interference with local communications.

The EUT is placed on an insulating support 10cm above the ground reference plane. On all cables to be tested, coupling and de-coupling networks are inserted. These coupling and de-coupling networks are placed directly on the ground reference plane between 10 to 30 cm away from the EUT. All cables shall be located between 3 to 5 cm above the ground reference plane wherever possible.

Where the EUT is provided with one or more dedicated earth terminals, they are connected to the ground reference plane through a de-coupling network such that the 50/60 Hz impedance is maintained.

Where the EUT is comprised of many sub-units, each sub-unit shall be tested separately unless the inter-connecting cables are less than 1 meter.

Where the EUT has several cables placed in close proximity over a length of more than 10 meters, they shall be treated as one cable and current injection shall be applied.

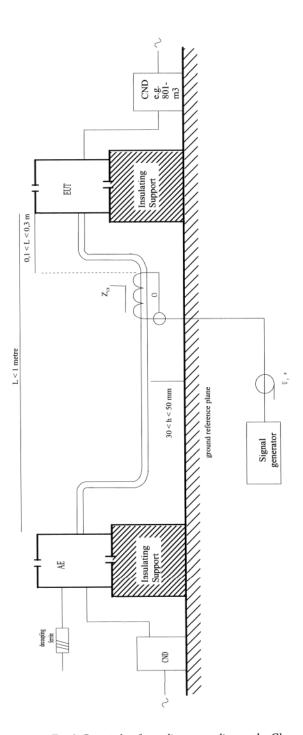


Fig 1. Principle of coupling according to the Clamp Injection Method.

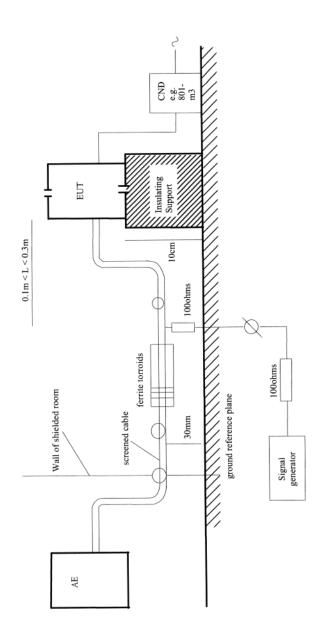


Fig 2. Principle of Direct Coupling to Screened Cables

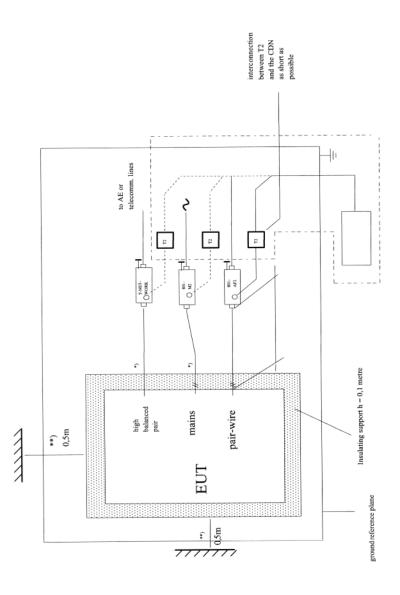


Fig. 3 Test setup for a single unit system for the immunity method to Conducted RF Disturbances

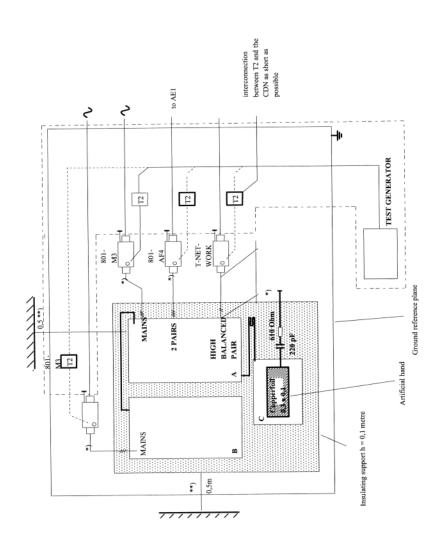


Fig. 4. Test setup for a multi-unit system for immunity method to Conducted RF Disturbances

POWER MAGNETIC FIELD IMMUNITY @ EN 61000-4-8 6.4.

INTRODUCTION 6.4.1.

These tests were conducted on a sample of the equipment for the purpose of Verification compliance with International Standard IEC 61000-4-8 - Electromagnetic Compatibility - Power Frequency Magnetic Field Immunity.

OBJECTIVE 6.4.2.

To determine the effect of power line magnetic fields on the device under test in conformance with IEC 61000-4-8 -Electromagnetic Compatibility - Power Frequency Magnetic Field Immunity.

THE SEVERITY LEVELS TO BE MET ARE AS FOLLOWS: 6.4.3.

FREQUENCY (Hz)	MAGNETIC FIELD (A/m)	DEGRADATION ALLOWED
50 Hz	3.0	No degradation allowed
50 Hz	30.0	CRT display interference allowed

TEST APPLICATION AND SETUP 6.5.

TEST METHOD #1: USING A HELMHOLTZ COIL. 6.5.1.

The magnetic field produced in a Helmholtz Coil is uniform and a well known function of the coils radius and coil current given by the following:

$$H = \underbrace{8NI}_{r*sqrt(125)} A/m$$

where:

H: Magnetic Field in A/m

Current present in coil in amps

N: Number of turns in each coil

R: Radius of Coil in meters

The Helmholtz coil used has the following characteristics: r = 0.5 m, N = 103

The relationship between H and I is therefore given by:

$$H = \frac{8*(103)*I}{0.5*sqrt(125)} A/m = 147.4*I$$

$$H(dBuA/m) = I(dBuA) + 43.37dB$$

For example: for H = 30 A/m, I = 106.2 dBuA or 203.5 mA

The current present in the Helmholtz Coil was monitored using a calibrated current probe connected to a spectrum analyzer display.

The following general provisions applied:

- The EUT was place at the center of the Helmholz Coil.
- The purity of the signal power delivered to the Helmholz Coil was such that it did not affect the uniformity nor the frequency of the magnetic field.
- At frequencies where EUT was found to respond most to the generated magnetic field, a sufficient time was spent at these sensitive frequencies to record the full immunity response.

- Cables connected to the EUT were fixed in position typical of an installed situation using non-reflective test fixtures.
- The EUT was operated at full load with DC output voltage level and current monitored by digital True RMS meters.
- The indicator LEDs, DC output current and voltage were monitored for any unexpected changes subjected to the presence of Magnetic Fields produced by a Helmholtx coil.
- The signal source frequency was slowly varied through the required frequency range. When this activity was performed in discrete steps, manual scanning would be performed around worst case points until the worst case frequency value was obtained.

TEST METHOD #2: USING AN INDUCTION COIL, REF. IEC 61000-4-8, PARA. 6.2.1 6.5.2.

The induction coil, connected to the test generator, was used to generate a field strength corresponding to the selected test level and the define homogeneity.

The single, square induction coil is made of copper material, of such cross-section and mechanical arrangement as to facilitate its stable positioning during tests.

The induction coil dimensions are adjustable to envelop the EUT at different size; the coil dimensions are such as to give a minimum distance of coil inductors to EUT walls equal to 1/3 of the dimension of the EUT considered.

The test volume is determined by the testing area of the coil (60%x60% of each side) multiplied by a depth corresponding to 50% of the shorter side of the coil.

Calibration of the Induction Coil, Coil Factor

The induction coil is calibrated in their operating condition, before conducting the test (without the EUT, in free space condition).

The EUT with the correct dimensions for the EUT dimensions, is positioned at 1m minimum distance from the wall of the laboratory and any magnetic material, by using insulating supports, and is connected to the test generator.

The magnetic field sensor is used to verify the magnetic field strength generated by the induction coil.

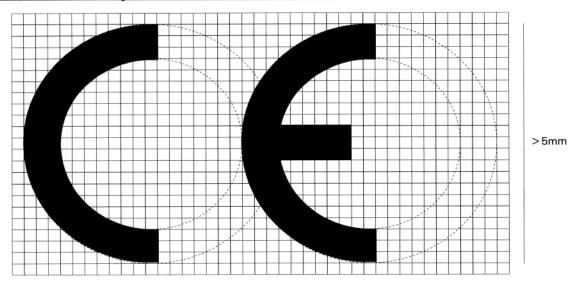
The field sensor is positioned at the center of the induction coil (without the EUT) and with suitable orientation to detect the maximum value of the field.

The current in the induction coil is adjusted to obtained the field strength specified by the test level.

The calibration is carried out at the power frequency (50 Hz).

EXHIBIT 7. LABELLING REQUIREMENTS

The CE Mark with respect to the EMC Directive 89/336/EEC



The CE mark shall consist of the initials "CE" taking the following form

- If the CE marking is reduced or enlarged, the proportions given in the above graduated drawing must be respected.
- Where apparatus is the subject of other Directives covering other aspects and which also provide for the CE conformity
 marking, the latter shall indicate that the appliances are also presumed to conform to those other Directives.
- However, where one or more of these Directives allow the manufacturer, during a transitional period, to choose which
 arrangements to apply, the CE mark shall indicate conformity only to the Directives applied by the manufacturer. In this
 case, particulars of the Directive applied, as published in the Official Journal of the European Communities, must be
 given in the documents, notices or instructions required by the Directives and accompanying such apparatus.

The various components of the CE marking must have substantially the same vertical dimension, which may not be less than 5mm.